

ECL SJ-2810 Series

Description

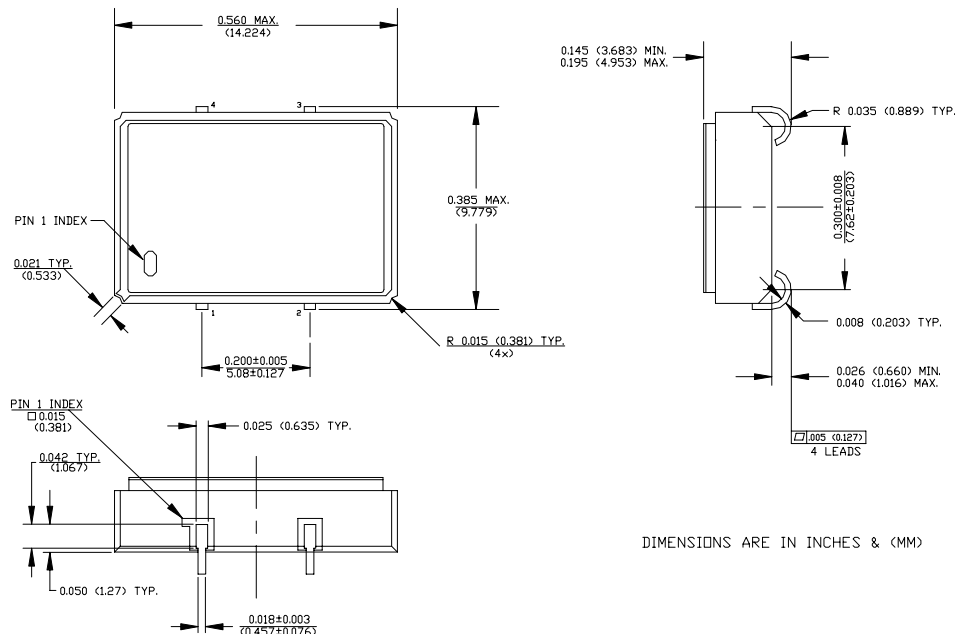
The **SJ-2810 Series** of quartz crystal oscillators provide ECL 10K and 10KH series compatible signals in a ceramic SMD package. Systems designers may now specify space-saving, cost-effective packaged ECL oscillators to meet their timing requirements.

Features

- Wide frequency range—18.0MHz to 250.0MHz
- User specified tolerance available
- Will withstand vapor phase temperatures of 253°C for 4 minutes maximum
- Space-saving alternative to discrete component oscillators
- High shock resistance, to 3000g
- Metal lid electrically connected to ground to reduce EMI
- Low Jitter
- ECL 10K and 10KH series compatible output on Pin 3, complement on Pin 1
- High Q Crystal actively tuned oscillator circuit
- Power supply decoupling internal
- No internal PLL avoids cascading PLL problems
- High frequencies due to proprietary design
- Gold plated leads - Solder dipped leads available upon request
- RoHS Compliant, Lead Free Construction

Electrical Connection

Pin	Connection
1	Output Complement
2	V_{EE} -5.2V
3	Output
4	V_{CC} Ground



SJ-2810 Series Continued
ECL

Rev. H

Operating Conditions and Output Characteristics

Electrical Characteristics

Parameter	Symbol	Conditions	Min	Typical	Max
Frequency	-----	-----	18.0MHz	-----	250.0MHz
Duty Cycle	-----	@ V _{CC} -1.29V	45/55%	-----	55/45%
Logic 0 ⁽²⁾	V _{OL}	-----	V _{CC} -1.95V	-----	V _{CC} -1.60V
Logic 1 ⁽²⁾	V _{OH}	-----	V _{CC} -1.02V	-----	V _{CC} -0.74V
Rise & Fall Time	tr,tf	20-80%V _O with 50 ohm load to V _{CC} -2V	-----	1.0 ns	1.5 ns
Tpd ⁽⁴⁾	-----	-----	-0.5 ns	-----	+0.5 ns
Jitter, RMS ⁽³⁾	-----	-----	-----	-----	5 psec
Frequency Stability ⁽¹⁾	dF/F	Overall conditions including: voltage, calibration, temp., 10 yr aging, shock, vibration	-100ppm	-----	+100ppm

General Characteristics

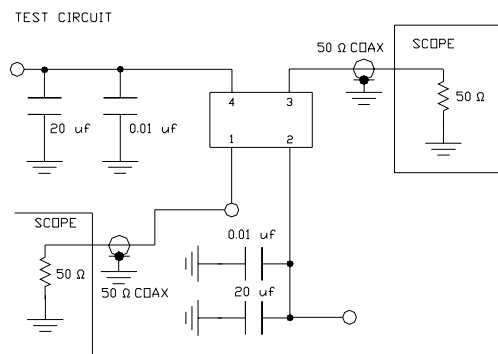
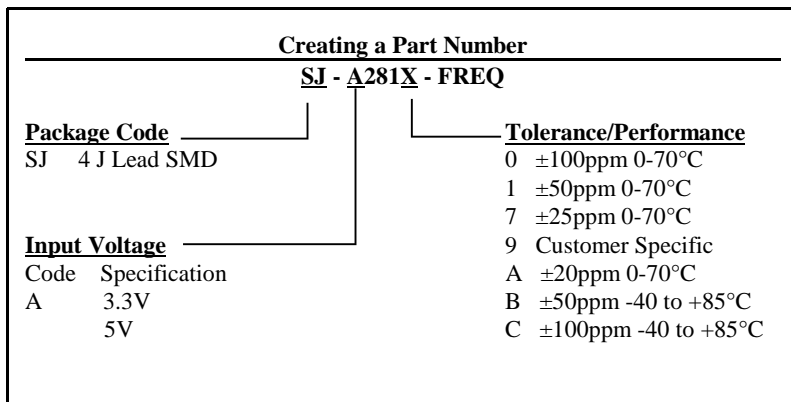
Parameter	Symbol	Conditions	Min	Typical	Max
Supply Voltage	V _{EE}	-----	-5.46V	-5.2V	-4.94V
Supply Current	I _{EE}	50 ohm termination To 2.00V below V _{CC}	0.0 mA	-----	80 mA
Output current	I _O	Low level Output Current	0.0 mA	-----	±50.0 mA
Operating temperature	T _A	-----	0°C	-----	70°C
Storage temperature	T _S	-----	-55°C	-----	125°C
Power Dissipation	P _D	-----	-----	-----	437 mW
Lead temperature	T _L	Soldering, 10 sec.	-----	-----	300°C
Load	50 Ohm to V _{CC} -2V or Thevenin Equivalent, Bias Required	-----	-----	-----	-----
Start-up time	t _S	-----	-----	2 ms	10 ms

Environmental and Mechanical Characteristics

Mechanical Shock	Per MIL-STD-202, Method 213, Condition E
Thermal Shock	Per MIL-STD-833, Method 1011, Condition A
Vibration	0.060" double amplitude 10 Hz to 55 Hz, 35g's 55Hz to 2000 Hz
Soldering Condition	300°C for 10 seconds
Hermetic Seal	Leak rate less than 1 x 10 ⁻⁸ atm.cc/sec of helium
ESD Sensitivity	Human Body Model per ON Semiconductor 10kH series ECL: 500V min.

Footnotes:

- Standard frequency stability (±20,±25,±50ppm & others available)
- V_{OL}, V_{OH}, referenced to ground (V_{CC}) with V_{EE} = -5.2V
- Jitter performance is frequency dependent. Please contact factory for full characterization.
RMS jitter bandwidth of 12kHz to 20MHz.
- Tpd is phase shift between the falling edge of pin 3 at V_{CC}-1.29V and rising edge of pin 1 at V_{CC}-1.29V.



TEST CIRCUIT USES A SPLIT SUPPLY OF +2V AND -3.2V FOR EASE OF TESTING.